NSN 5962-01-445-0691

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
F-15i
Features Provided:
Electrostatic sensitive and monolithic and programmable and tested to mil-std-883
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Criticality Code Justification:
Cbbl and feat
Product Name:
Microcircuit, memory, digital cmos field programmable gate array, 8000 gates, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Special Features:
Altered item made from 5962-9215602mxx
Terminal Type And Quantity:
176 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A458a0